

Test Report Page: 1 of 16 No.: ETR24800008 Date: 08-Aug-2024

POWERCHIP SEMICONDUCTOR MANUFACTURING CORP. NO.12, LI-HSIN RD.1, HSINCHU SCIENCE PARK, HSINCHU, TAIWAN, R.O.C.

The following sample(s) was/were submitted and identified by the applicant as:

POWERCHIP SEMICONDUCTOR MANUFACTURING CORP. Sample Submitted By

Sample Name 12 INCH WAFER

Style/Item No. LOGIC PROCESS WAFER

Sample Receiving Date 01-Aug-2024

Testing Period 01-Aug-2024 to 08-Aug-2024

(1) As specified by client, with reference to RoHS 2011/65/EU Annex II and amending **Test Requested**

Directive (EU) 2015/863 to determine Cadmium, Lead, Mercury, Cr(VI), PBBs, PBDEs,

DBP, BBP, DEHP, DIBP contents in the submitted sample(s).

(2) Please refer to next pages for the other item(s).

Test Results Please refer to following pages.

Conclusion Based on the performed tests on submitted sample(s), the test results of Cadmium,

> Lead, Mercury, Cr(VI), PBBs, PBDEs, DBP, BBP, DEHP, DIBP comply with the limits as set by RoHS Directive (EU) 2015/863 amending Annex II to Directive 2011/65/EU.

Signed for and on behalf 💸 SĞS TAIWAN LTD. Chemical Laboratory - Taipei



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POWERCHIP SEMICONDUCTOR MANUFACTURING CORP. NO.12, LI-HSIN RD.1, HSINCHU SCIENCE PARK, HSINCHU, TAIWAN, R.O.C.

Test Part Description

No.1 : WAFER

Test Result(s)

Test Item(s)	Method	Unit	MDL	Result	Limit
				No.1	*
Cadmium (Cd)	With reference to IEC 62321-5: 2013,	mg/kg	2	n.d.	100
	analysis was performed by ICP-OES.				
Lead (Pb)	With reference to IEC 62321-5: 2013,	mg/kg	2	n.d.	1000
	analysis was performed by ICP-OES.				
Mercury (Hg)	With reference to IEC 62321-4: 2013+	mg/kg	2	n.d.	1000
	AMD1: 2017, analysis was performed				
	by ICP-OES.				
Hexavalent Chromium Cr(VI)	With reference to IEC 62321-7-2: 2017,	mg/kg	8	n.d.	1000
	analysis was performed by UV-VIS.				
Monobromobiphenyl		mg/kg	5	n.d.	ı
Dibromobiphenyl		mg/kg	5	n.d.	1
Tribromobiphenyl		mg/kg	5	n.d.	1
Tetrabromobiphenyl		mg/kg	5	n.d.	ı
Pentabromobiphenyl		mg/kg	5	n.d.	ı
Hexabromobiphenyl		mg/kg	5	n.d.	-
Heptabromobiphenyl		mg/kg	5	n.d.	1
Octabromobiphenyl		mg/kg	5	n.d.	1
Nonabromobiphenyl		mg/kg	5	n.d.	ī
Decabromobiphenyl		mg/kg	5	n.d.	ì
Sum of PBBs	With reference to IEC 62321-6: 2015,	mg/kg	=	n.d.	1000
Monobromodiphenyl ether	analysis was performed by GC/MS.	mg/kg	5	n.d.	ı
Dibromodiphenyl ether		mg/kg	5	n.d.	I
Tribromodiphenyl ether		mg/kg	5	n.d.	-
Tetrabromodiphenyl ether		mg/kg	5	n.d.	-
Pentabromodiphenyl ether		mg/kg	5	n.d.	-
Hexabromodiphenyl ether		mg/kg	5	n.d.	-
Heptabromodiphenyl ether		mg/kg	5	n.d.	-
Octabromodiphenyl ether		mg/kg	5	n.d.	-
Nonabromodiphenyl ether		mg/kg	5	n.d.	-
Decabromodiphenyl ether		mg/kg	5	n.d.	-
Sum of PBDEs		mg/kg	-	n.d.	1000

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POWERCHIP SEMICONDUCTOR MANUFACTURING CORP. NO.12, LI-HSIN RD.1, HSINCHU SCIENCE PARK, HSINCHU, TAIWAN, R.O.C.

Test Item(s)	Method	Unit	MDL	Result	Limit
				No.1	
Butyl benzyl phthalate (BBP)		mg/kg	50	n.d.	1000
Dibutyl phthalate (DBP)		mg/kg	50	n.d.	1000
Di-(2-ethylhexyl) phthalate (DEHP)		mg/kg	50	n.d.	1000
Diisobutyl phthalate (DIBP)		mg/kg	50	n.d.	1000
Diisodecyl phthalate (DIDP) (CAS		mg/kg	50	n.d.	-
No.: 26761-40-0, 68515-49-1)					
Diisononyl phthalate (DINP) (CAS		mg/kg	50	n.d.	-
No.: 28553-12-0, 68515-48-0)	With reference to IEC 62321-8: 2017,				
Di-n-octyl phthalate (DNOP) (CAS	analysis was performed by GC/MS.	mg/kg	50	n.d.	-
No.: 117-84-0)					
Di-n-pentyl phthalate (DNPP) (CAS		mg/kg	50	n.d.	-
No.: 131-18-0)					
Di-n-hexyl phthalate (DNHP) (CAS		mg/kg	50	n.d.	-
No.: 84-75-3)					
Bis(2-methoxyethyl) phthalate		mg/kg	50	n.d.	-
(DMEP) (CAS No.: 117-82-8)					
Hexabromocyclododecane (HBCDD)	With reference to IEC 62321-9: 2021,	mg/kg	20	n.d.	-
and all major diastereoisomers	analysis was performed by GC/MS.				
identified (α- HBCDD, β- HBCDD, γ-					
HBCDD) (CAS No.: 25637-99-4,					
3194-55-6 (134237-51-7, 134237-					
50-6, 134237-52-8))					
Fluorine (F) (CAS No.: 14762-94-8)		mg/kg	50	n.d.	-
Chlorine (Cl) (CAS No.: 22537-15-1)	With reference to BS EN 14582: 2016,	mg/kg	50	n.d.	-
Bromine (Br) (CAS No.: 10097-32-2)	analysis was performed by IC.	mg/kg	50	n.d.	-
lodine (I) (CAS No.: 14362-44-8)		mg/kg	50	n.d.	-
Arsenic (As) (CAS No.: 7440-38-2)	With reference to US EPA 3052: 1996,	mg/kg	2	n.d.	-
	analysis was performed by ICP-OES.				
Beryllium (Be) (CAS No.: 7440-41-7)	With reference to US EPA 3052: 1996,	mg/kg	2	n.d.	-
	analysis was performed by ICP-OES.				
Antimony (Sb) (CAS No.: 7440-36-0)	With reference to US EPA 3052: 1996,	mg/kg	2	n.d.	-
	analysis was performed by ICP-OES.				
Red Phosphorus	Analysis was performed by Pyrolyzer-	**	-	Negative	-
	GC/MS.				

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POWERCHIP SEMICONDUCTOR MANUFACTURING CORP.
NO.12, LI-HSIN RD.1, HSINCHU SCIENCE PARK, HSINCHU, TAIWAN, R.O.C.

Test Item(s)	Method	Unit	MDL	Result	Limit
				No.1	
11/63-23-1 and its saits)	Modified EN 17681-1: 2022 & EN	mg/kg	0.01	n.d.	-
IPARTILIAROACTANAIC ACID AND ITS SAITS	17681-2: 2022, analysis was performed by LC/MS/MS.	mg/kg	0.01	n.d.	-

Note:

- 1. mg/kg = ppm; 0.1wt% = 0.1% = 1000ppm
- 2. MDL = Method Detection Limit
- 3. n.d. = Not Detected (Less than MDL)
- 4. "-" = Not Regulated
- 5. **= Qualitative analysis (No Unit)
- 6. Negative = Undetectable ; Positive = Detectable
- 7. Unless otherwise stated, the decision rule for conformity reporting is based on Binary Statement for Simple Acceptance Rule (w=0) stated in ILAC-G8:09/2019. According to this rule, the judgement of conformity is based on the comparing test results with limits.

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POWERCHIP SEMICONDUCTOR MANUFACTURING CORP. NO.12, LI-HSIN RD.1, HSINCHU SCIENCE PARK, HSINCHU, TAIWAN, R.O.C.

PFAS Remark:

The quantitative technology of PFAS is to analyze the specific structure of PFAS substances. However, PFAS acid and its salts with the same carbon number group have the same specific structure that can be identified. The tested results of the analyzed specific structure cannot be distinguished to identify the contribution from PFAS acid or its salts. Therefore, the tested results display the sum of concentrations of PFAS acids and its salts with the same carbon number group. The concentration of PFAS substances in the below table have been included in the tested results, please refer to the table for relevant information: (The listed PFAS substances are examples only, it do not include all PFAS salts with the same carbon number group.)

Group Name	Substance Name	CAS No.
	Perfluorooctane sulfonates (PFOS)	1763-23-1
	Potassium perfluorooctanesulfonate (PFOS-K)	2795-39-3
	Perfluorooctanesulfonic acid, lithium salt (PFOS-Li)	29457-72-5
	Perfluorooctanesulfonic acid, ammonium salt (PFOS-NH ₄)	29081-56-9
	Perfluorooctane sulfonate diethanolamine salt (PFOS-NH(OH) ₂)	70225-14-8
	Perfluorooctanesulfonic acid, tetraethylammonium salt (PFOS- $N(C_2H_5)_4$)	56773-42-3
	N-decyl-N,N-dimethyldecan-1-aminium 1,1,2,2,3,3,4,4,5,5,6,6,7,7,8,8,8-heptadecafluorooctane-1- sulfonate (PFOS-DDA)	251099-16-8
	TetrabutylAmmonium perfluorooctanesulfonate (PFOS-N(C ₄ H ₉) ₄)	111873-33-7
	Perfluorooctane sulfonyl fluoride (POSF)	307-35-7
PFOS, its salts & derivatives	Perfluorooctanesulfonic acid, magnesium salt (PFOS-Mg)	91036-71-4
	Perfluorooctanesulfonic acid, sodium salt (PFOS-Na)	4021-47-0
	Piperidine 1,1,2,2,3,3,4,4,5,5,6,6,7,7,8,8,8- heptadecafluorooctanesulfonate	71463-74-6
	Perfluorooctanesulfonate (anion)	45298-90-6
	1-Octanesulfonic acid, 1,1,2,2,3,3,4,4,5,5,6,6,7,7,8,8,8-heptadecafluoro-, compd. with N,N-diethylethanamine (1:1) (PFOS-N(C_2H_5) ₃)	54439-46-2
	Methanaminium, N,N,N-trimethyl-, 1,1,2,2,3,3,4,4,5,5,6,6,7,7,8,8,8-heptadecafluoro-1- octanesulfonate (1:1) (PFOS-N(CH ₃) ₄)	56773-44-5
		56773-56-9

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NO.12, LI-HSIN RD.1, HSINCHU SCIENCE PARK, HSINCHU, TAIWAN, R.O.C.

Group Name	Substance Name	CAS No.
	1-Butanaminium, N,N-dibutyl-N-methyl-, 1,1,2,2,3,3,4,4,5,5,6,6,7,7,8,8,8-heptadecafluoro-1- octanesulfonate (1:1) (PFOS-N(C ₄ H ₉) ₃ (CH ₃))	124472-68-0
	lodonium, bis[4-(1,1-dimethylethyl)phenyl]-, 1,1,2,2,3,3,4,4,5,5,6,6,7,7,8,8,8-heptadecafluoro-1- octanesulfonate (1:1)	213740-80-8
	Sulfonium, diphenyl(2,4,6-trimethylphenyl)-, 1,1,2,2,3,3,4,4,5,5,6,6,7,7,8,8,8-heptadecafluoro-1- octanesulfonate (1:1)	258341-99-0
PFOS, its salts & derivatives	Pyridinium, 1-hexadecyl-, 1,1,2,2,3,3,4,4,5,5,6,6,7,7,8,8,8-heptadecafluoro-1-octanesulfonate (1:1)	334529-63-4
	1-Decanaminium, N,N,N-triethyl-, 1,1,2,2,3,3,4,4,5,5,6,6,7,7,8,8,8-heptadecafluoro-1- octanesulfonate (1:1)	773895-92-4
	Tetrabutylphosphonium perfluorooctane sulfonate (PFOS- $P(C_4H_9)_4$))	2185049-59-4
	Perfluorooctanesulfonic acid diethylamine salt (PFOS-C ₄ H ₁₁ N)	2205029-08-7
	$\label{eq:heptyldimethyl} Heptyldimethyl \ \{2-[(2-methylprop-2-enoyl)oxy]ethyl\} azanium \\ perfluorooctanesulfonate (PFOS-C_{15}H_{30}NO_2)$	1203998-97-3
	1-Octanesulfonic acid, 1,1,2,2,3,3,4,4,5,5,6,6,7,7,8,8,8- heptadecafluoro-, 1,1'-anhydride (PFOSAN)	423-92-7
	Perfluorooctanoic acid (PFOA)	335-67-1
	Sodium perfluorooctanoate (PFOA-Na)	335-95-5
	Potassium perfluorooctanoate (PFOA-K)	2395-00-8
	Silver perfluorooctanote (PFOA-Ag)	335-93-3
	Perfluorooctanoyl fluoride (PFOA-F)	335-66-0
	Ammonium pentadecafluorooctanoate (APFO)	3825-26-1
PFOA, its salts & derivatives	Lithium perfluorooctanoate (PFOA-Li)	17125-58-5
	Cobalt perfluorooctanoate (PFOA-Co)	35965-01-6
	Cesium perfluorooctanoate (PFOA-Cs)	17125-60-9
	Octanoic acid, 2,2,3,3,4,4,5,5,6,6,7,7,8,8,8-pentadecafluoro-, chromium(3+) (PFOA-Cr(3 ⁺))	68141-02-6
	Pentadecafluorooctanoic acidpiperazine (2/1)PFOA- $\mathrm{NH}(\mathrm{C_4H_{10}N})$	423-52-9
	Pentadecafluorooctanoate (anion)	45285-51-6
	Perfluorooctanoic Anhydride	33496-48-9

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POWERCHIP SEMICONDUCTOR MANUFACTURING CORP. NO.12, LI-HSIN RD.1, HSINCHU SCIENCE PARK, HSINCHU, TAIWAN, R.O.C.

Group Name	Substance Name	CAS No.
	Ethanaminium, N,N,N-triethyl-, 2,2,3,3,4,4,5,5,6,6,7,7,8,8,8-pentadecafluorooctanoate (1:1)	98241-25-9
	Tetramethylammoniumperfluoroctanoat	32609-65-7
	1-Propanaminium, N,N,N-tripropyl-, 2,2,3,3,4,4,5,5,6,6,7,7,8,8,8-pentadecafluorooctanoate (1:1)	277749-00-5
	Octanoic acid, 2,2,3,3,4,4,5,5,6,6,7,7,8,8,8-pentadecafluoro-, potassium salt, hydrate (1:1:2) (PFOA-K(H ₂ O) ₂)	98065-31-7
PFOA, its salts & derivatives	Octanoic acid, 2,2,3,3,4,4,5,5,6,6,7,7,8,8,8-pentadecafluoro-, compd. with ethanamine (1:1) (PFOA-C ₂ H ₇ N)	1376936-03-6
	Octanoic acid, pentadecafluoro-, compd. with pyridine (1:1) (9CI) (PFOA- C_5H_5N)	95658-47-2
	Pentadecafluorooctanoic acid- 1-phenylpiperazine(1:1) (PFOA- $C_{10}H_{14}N_2$)	1514-68-7
	$ \begin{array}{lll} \hbox{1-Octanaminium, N,N,N-trimethyl-, 2,2,3,3,4,4,5,5,6,6,7,7,8,8,8-pentadecafluorooctanoate (1:1) (PFOA- $C_{11}H_{26}N)$ } \end{array} $	927835-01-6

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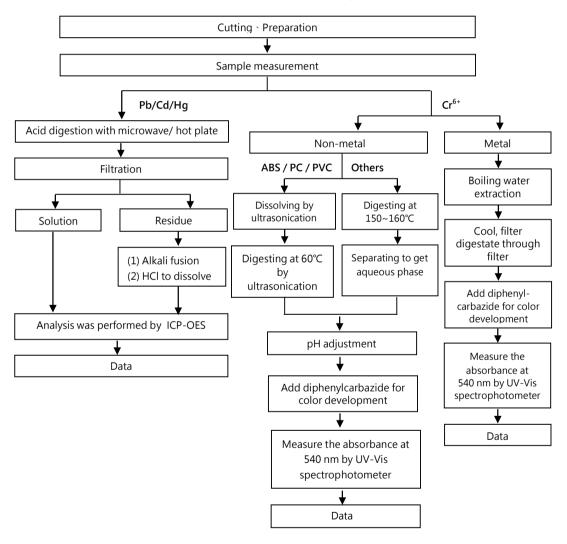
Date: 08-Aug-2024

POWERCHIP SEMICONDUCTOR MANUFACTURING CORP. NO.12, LI-HSIN RD.1, HSINCHU SCIENCE PARK, HSINCHU, TAIWAN, R.O.C.

Analytical flow chart of heavy metal

These samples were dissolved totally by pre-conditioning method according to below flow chart.

(Cr⁶⁺ test method excluded)



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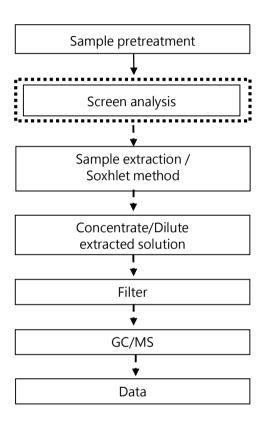
POWERCHIP SEMICONDUCTOR MANUFACTURING CORP. NO.12, LI-HSIN RD.1, HSINCHU SCIENCE PARK, HSINCHU, TAIWAN, R.O.C.

Analytical flow chart - PBBs / PBDEs

First testing process

Optional screen process

Confirmation process



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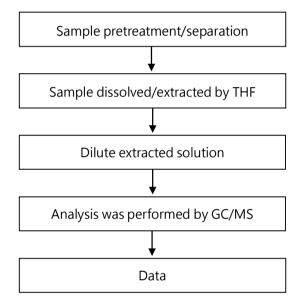


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POWERCHIP SEMICONDUCTOR MANUFACTURING CORP. NO.12, LI-HSIN RD.1, HSINCHU SCIENCE PARK, HSINCHU, TAIWAN, R.O.C.

Analytical flow chart - Phthalate

[Test method: IEC 62321-8]



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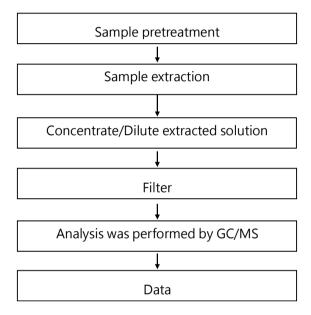
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POWERCHIP SEMICONDUCTOR MANUFACTURING CORP. NO.12, LI-HSIN RD.1, HSINCHU SCIENCE PARK, HSINCHU, TAIWAN, R.O.C.

Analytical flow chart - HBCDD



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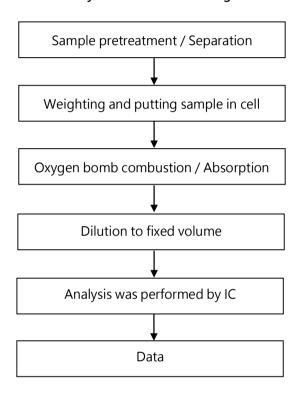
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POWERCHIP SEMICONDUCTOR MANUFACTURING CORP. NO.12, LI-HSIN RD.1, HSINCHU SCIENCE PARK, HSINCHU, TAIWAN, R.O.C.

Analytical flow chart - Halogen



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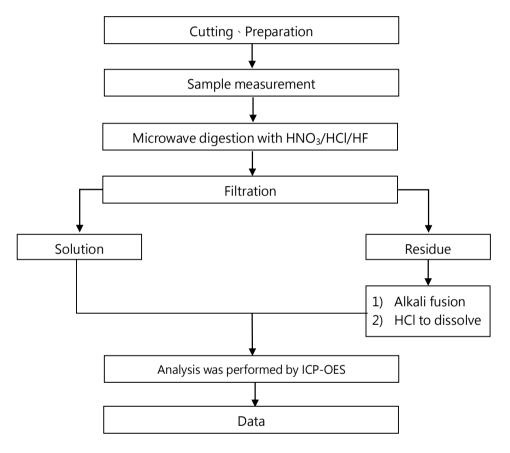
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POWERCHIP SEMICONDUCTOR MANUFACTURING CORP. NO.12, LI-HSIN RD.1, HSINCHU SCIENCE PARK, HSINCHU, TAIWAN, R.O.C.

Analytical flow chart of elements (Heavy metal included)

These samples were dissolved totally by pre-conditioning method according to below flow chart.

【Reference method: US EPA 3051A \ US EPA 3052】



^{*} US EPA 3051A method does not add HF.

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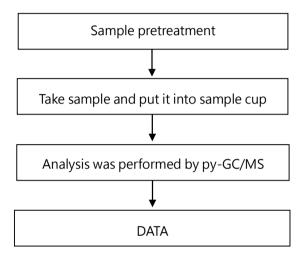
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Analytical flow chart - Red phosphorus



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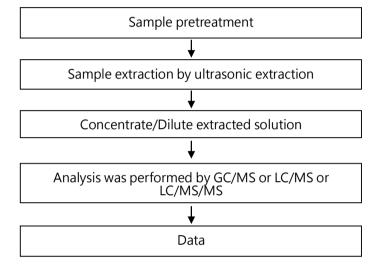


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Analytical flow chart - PFAS (including PFOA/PFOS/its related compound, etc.)



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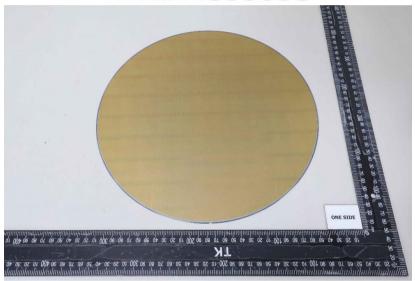
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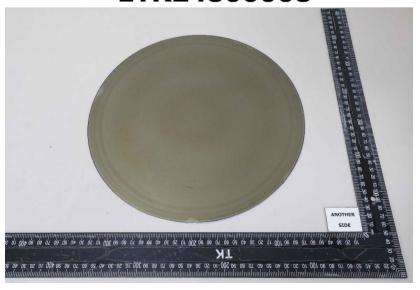
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* The tested sample / part is marked by an arrow if it's shown on the photo. *

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** End of Report **

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